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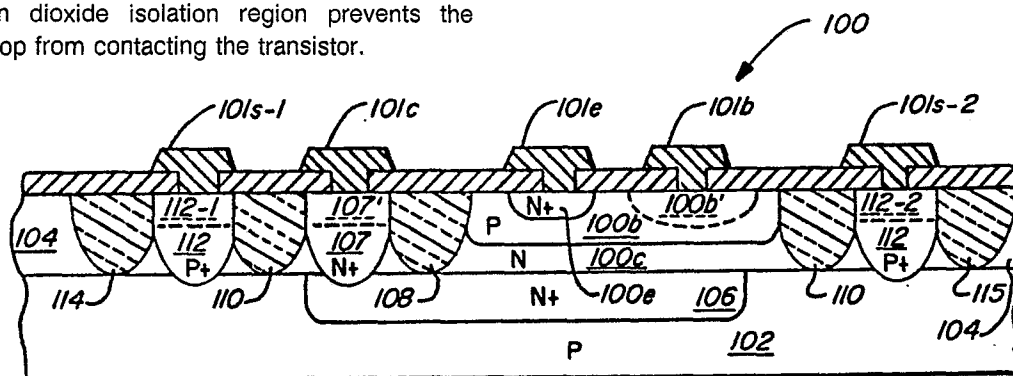
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54 **Bipolar integrated circuit having an improved isolation and substrate connection, and method of preparing the same.**

57 A structure for isolating a bipolar transistor (100) from an adjacent transistor includes a first silicon dioxide isolation region (110) laterally surrounding the transistor and a conductive channel stop region (112) laterally surrounding the silicon dioxide isolation region. The channel stop region allows electrical potential of the substrate (102) to be controlled and the silicon dioxide isolation region prevents the channel stop from contacting the transistor.





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DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.4)
X	EP-A-146760 (IBM) * page 7, lines 7 - 10; claims 1-4; figure 6 * ---	1, 2, 5-13	H01L21/74 H01L21/76 H01L29/06
X	IBM TECHNICAL DISCLOSURE BULLETIN. vol. 27, no. 4B, September 1984, NEW YORK US page 2420 R. F. PENoyer.: "SEMICONDUCTOR SUBSTRATE CONTACT." * the whole document * ---	1, 3-13	
A	PATENT ABSTRACTS OF JAPAN vol. 6, no. 160 (E-126)(1038) 21 August 1982, & JP-A-57 80755 (MITSUBISHI) 20 May 1982, * the whole document * -----	1-13	
			TECHNICAL FIELDS SEARCHED (Int. Cl.4)
			H01L
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 04 MAY 1990	Examiner VANCRAEYNST F.
CATEGORY OF CITED DOCUMENTS X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document			